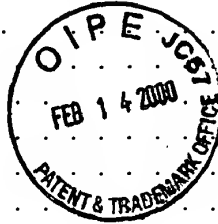


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 09/292,132
Filing Date April 14, 1999
Inventorship Salman Akram et al.
Assignee Micron Technology, Inc.
Group Art Unit 2812
Examiner S. Mulpuri
Attorney's Docket No. MI22-1171
Title Methods of Forming a Transistor Gate



RESPONSE TO NOVEMBER 9, 1999 OFFICE ACTION

#9/B
2/25/00
Purles

To: Assistant Commissioner for Patents
Washington, D.C. 20231

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)
Wells, St. John, Roberts, Gregory & Matkin P.S.
601 West First Avenue, Suite 1300
Spokane, WA 99201-3828

Sir:

Responsive to the Office Action dated November 9, 1999,
Applicant amends and remarks as follows:

AMENDMENTS

In the Claims

Please amend the claims as follows:

02/15/2000 UMAN11 00000023 09292132 36.00 DP
FC:103